

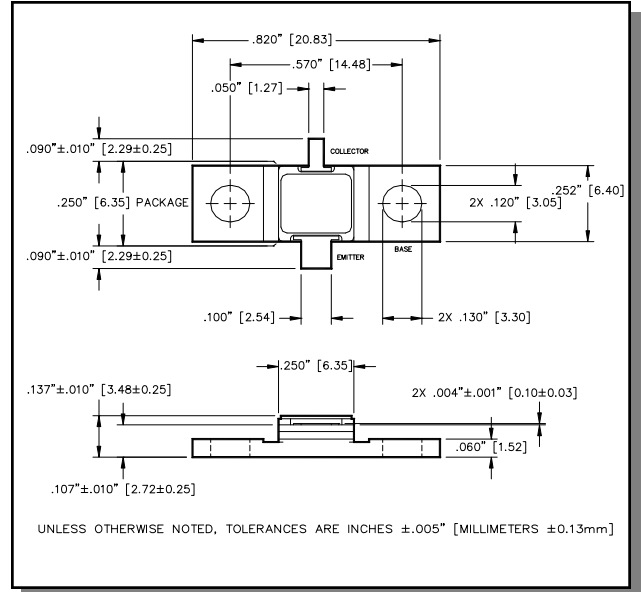
**Radar Pulsed Power Transistor**  
**11W, 3.1-3.4 GHz, 1μs Pulse, 10% Duty**

**M/A-COM Products**  
**Released, 10 Jul 07**

## Features

- NPN silicon microwave power transistors
- Common base configuration
- Broadband Class C operation
- High efficiency inter-digitized geometry
- Diffused emitter ballasting resistors
- Gold metallization system
- Internal input and output impedance matching
- Hermetic metal/ceramic package
- RoHS compliant

## Outline Drawing



## Absolute Maximum Ratings at 25°C

Parameter	Symbol	Rating	Units
Collector-Emitter Voltage	$V_{CES}$	60	V
Emitter-Base Voltage	$V_{EBO}$	3.0	V
Collector Current (Peak)	$I_C$	1.3	A
Power Dissipation @ +25°C	$P_{TOT}$	125	W
Storage Temperature	$T_{STG}$	-65 to +200	°C
Junction Temperature	$T_J$	200	°C

## Electrical Specifications: $T_C = 25 \pm 5^\circ\text{C}$ (Room Ambient )

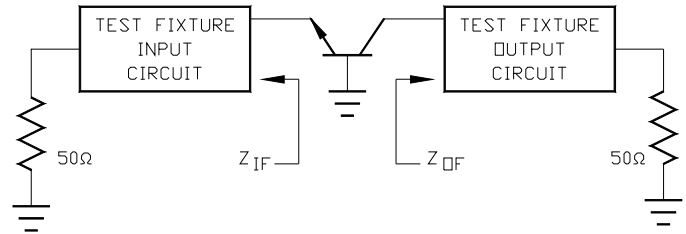
Parameter	Test Conditions	Frequency	Symbol	Min	Max	Units
Collector-Emitter Breakdown Voltage	$I_C = 12.5\text{mA}$		$BV_{CES}$	60	-	V
Collector-Emitter Leakage Current	$V_{CE} = 36\text{V}$		$I_{CES}$	-	1.25	mA
Thermal Resistance	$V_{CC} = 36\text{V}$ , $P_{out} = 11\text{W}$	$F = 3.1, 3.25, 3.4\text{ GHz}$	$R_{TH(JC)}$	-	1.4	°C/W
Input Power	$V_{CC} = 36\text{V}$ , $P_{out} = 11\text{W}$	$F = 3.1, 3.25, 3.4\text{ GHz}$	$P_{IN}$	-	1.74	W
Power Gain	$V_{CC} = 36\text{V}$ , $P_{out} = 11\text{W}$	$F = 3.1, 3.25, 3.4\text{ GHz}$	$G_P$	8.0	-	dB
Collector Efficiency	$V_{CC} = 36\text{V}$ , $P_{out} = 11\text{W}$	$F = 3.1, 3.25, 3.4\text{ GHz}$	$\eta_C$	35	-	%
Input Return Loss	$V_{CC} = 36\text{V}$ , $P_{out} = 11\text{W}$	$F = 3.1, 3.25, 3.4\text{ GHz}$	RL	-	-6	dB
Load Mismatch Tolerance	$V_{CC} = 36\text{V}$ , $P_{out} = 11\text{W}$	$F = 3.25\text{ GHz}$	VSWR-T	-	2:1	-

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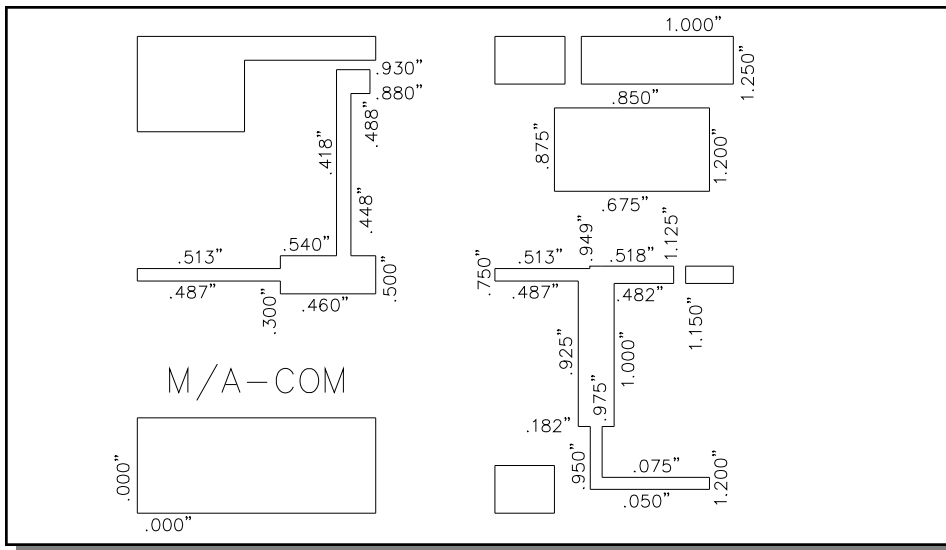
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### RF Test Fixture Impedance

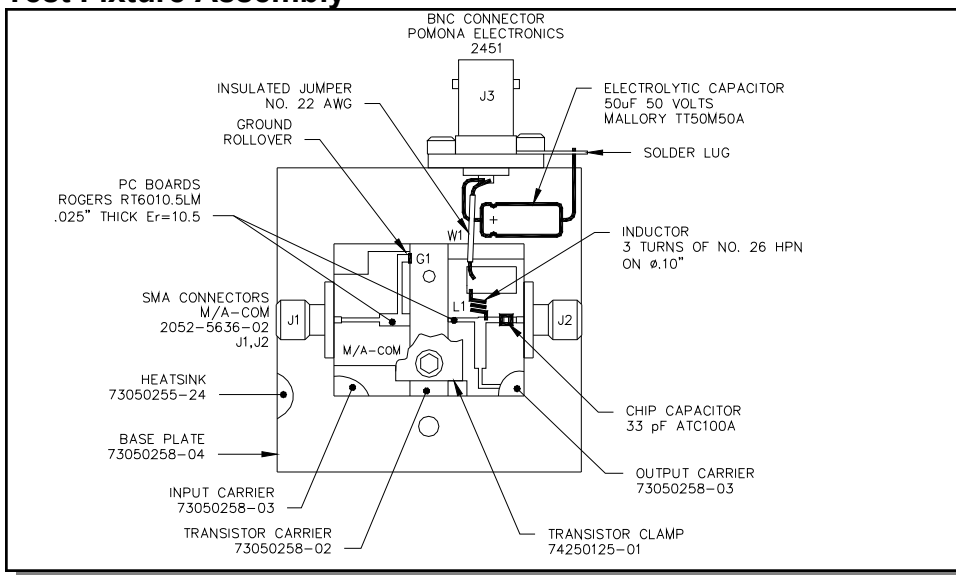
F (GHz)	Z <sub>IF</sub> (Ω)	Z <sub>OF</sub> (Ω)
3.10	17.5 - j8.5	90 + j37
3.25	15.0 - j8.2	58 + j7.0
3.40	13.0 - j8.0	30 + j14.5



### Test Fixture Circuit Dimensions



### Test Fixture Assembly



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- **North America** Tel: 800.366.2266 / Fax: 978.366.2266
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